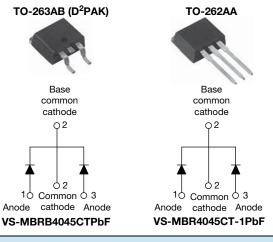
VS-MBRB4045CTPbF, VS-MBR4045CT-1PbF

Vishay Semiconductors

epoxy

High Performance Schottky Rectifier, 2 x 20 A



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SHA

PRODUCT SUMMARY	
Package	TO-263AB (D ² PAK), TO-262AA
I _{F(AV)}	40 A
V _R	45 V
V _F at I _F	0.58 V
I _{RM} max.	95 mA at 125 °C
T _J max.	150 °C
Diode variation	Common cathode
E _{AS}	20 mJ

FEATURES

High

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation

purity,

• Center tap TO-220, D²PAK and TO-262 packages



encapsulation for enhanced mechanical FREE strength and moisture resistance
Guard ring for enhanced ruggedness and long term

high temperature

- reliability
 Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND	CHARACTERISTICS		
SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}	Rectangular waveform (per device)	40	٨
I _{FRM}	T _C = 118 °C (per leg)	40	A
V _{RRM}		45	V
I _{FSM}	t _p = 5 μs sine	900	А
V _F	20 A _{pk} , T _J = 125 °C	0.58	V
TJ	Range	-65 to +150	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-MBRB4045CTPbF VS-MBR4045CT-1PbF	UNITS
Maximum DC reverse voltage	V _R	45	V
Maximum working peak reverse voltage	V _{RWM}	45	v

ABSOLUTE MAXIMUM RATI	NGS				
PARAMETER	SYMBOL	TEST COND	TIONS	VALUES	UNITS
Maximum average per leg		T _C = 118 °C, rated V _B		20	
forward current per device	I _{F(AV)}	$T_{\rm C} = 110$ C, lated $V_{\rm R}$		40	
Peak repetitive forward current per leg	I _{FRM}	Rated V_R , square wave, 20 kHz,	T _C = 118 °C	40	А
Maximum peak one cycle non-repetitive	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	900	
peak surge current per leg	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	210	
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 4.4 mH	1	20	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero Frequency limited by T _J maximu		3	А

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		20 A	T _{.1} = 25 °C	0.60	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	40 A	1j = 23 0	0.78	V
Maximum forward voltage drop	VFM ()	20 A	T _{.1} = 125 °C	0.58	
		40 A	1j = 125 C	0.75	
•• • • • •		T _J = 25 °C		1	
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 100 °C	Rated DC voltage	50	mA
		T _J = 125 °C		95	
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal ran	ge 100 kHz to 1 MHz), 25 °C	900	pF
Typical series inductance	L _S	Measured from top of ter	minal to mounting plane	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

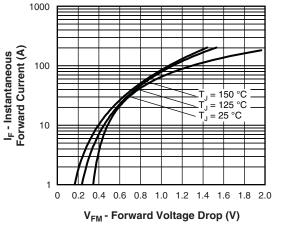
THERMAL - MECHANICAL	SPECIFIC	ATIONS		
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	TJ		-65 to +150	°C
Maximum storage temperature range	T _{Stg}		-65 to +175	U
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.5	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (Only for TO-220)	0.50	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (For D ² PAK and TO-262)	50	
Approving to weight			2	g
Approximate weight			0.07	oz.
Mounting torgue		Non-lubricated threads	6 (5)	kgf · cm
Mounting torque maximum		Non-Iubricated trireads	12 (10)	(lbf · in)
Marking davias		Case style D ² PAK	MBRB4	045CT
Marking device		Case style TO-262	MBR40	45CT-1

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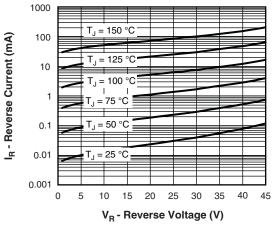


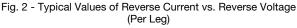
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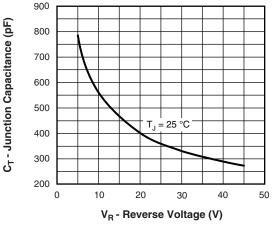


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

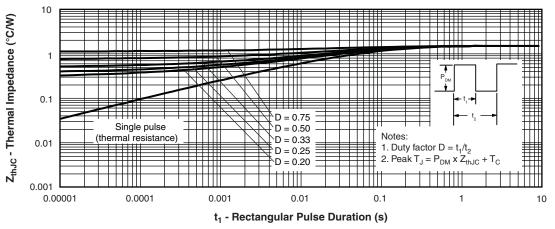
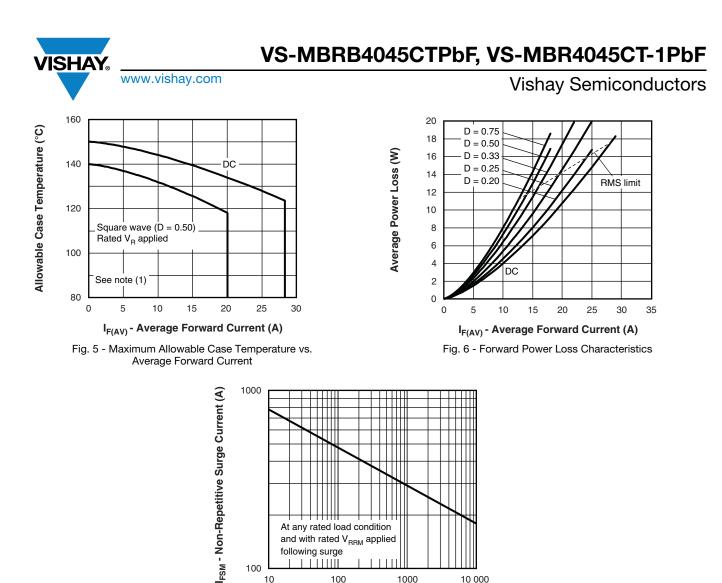


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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following surge 1 | | | | | |

100

t_p - Square Wave Pulse Duration (μs) Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

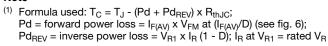
1000

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100

10







VS-MBRB4045CTPbF, VS-MBR4045CT-1PbF

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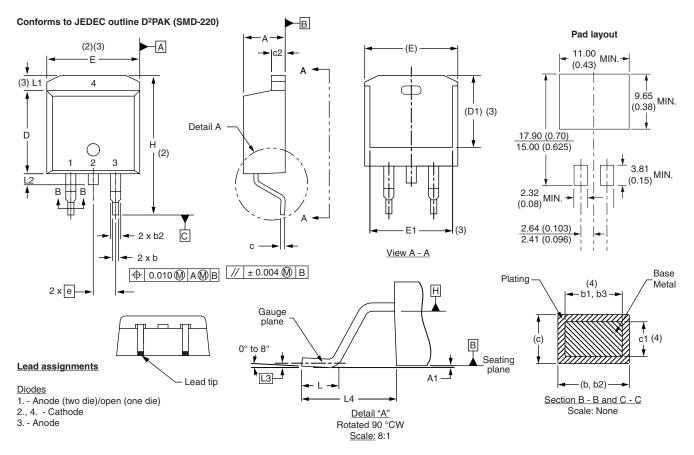
ORDERING INFORMATION TABLE

Device code	VS-	MBR	В	40	45	СТ	-1	TRL	PbF
		2	3	4	5	6	7	8	9
	1 · · · · · · · · · · · · · · · · · · ·	- Ess - B - N - Cur - Volt - CT - N 1	nay Serr ential pa = D ² PA one = Tr rent rati tage rati tage rati = esser one = D = TO-2 one = tu	art numh K [O-262 [ng (40 = ng (45 = tial part ² PAK [62 [7 Noi 7 = 40 A) = 45 V) numbe 3 = B 3 Noi	ne 1 r			
	<u> </u>	• TI	RL = tap RR = tap	e and re	eel (left				
	9		bF = lea = lead (. ,					be)

LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95014
Part marking information	www.vishay.com/doc?95008
Packaging information	www.vishay.com/doc?95032
SPICE model	www.vishay.com/doc?95296

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D²PAK, TO-262



DIMENSIONS - D²PAK in millimeters and inches

SHA

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

INCHES

MILLIMETERS

⁽⁷⁾ Outline conforms to JEDEC outline TO-263AB

Notes

 $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994 $\,$

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only
- ⁽⁵⁾ Datum A and B to be determined at datum plane H
- ⁽⁶⁾ Controlling dimension: inch

Document Number: 95014 Revision: 31-Mar-09

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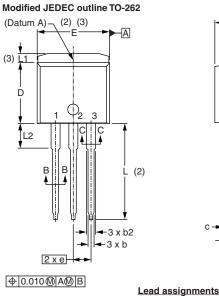
Outline Dimensions

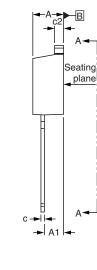
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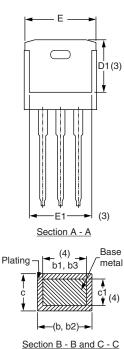
D²PAK, TO-262



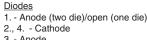
DIMENSIONS - TO-262 in millimeters and inches

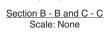






Lead tip





SYMBOL	MILLIN	METERS	INCI	NOTES	
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

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actual package outline

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the

3. - Anode



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